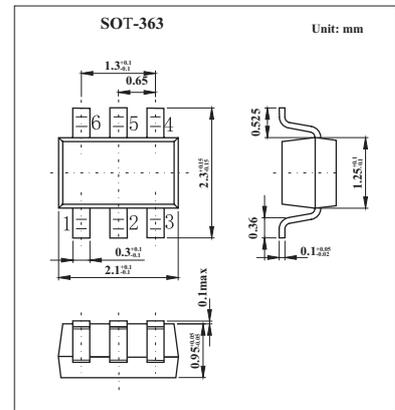
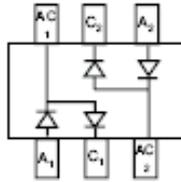


## Quad Surface Mount Switching Diode Array KAV99DW(BAV99DW)

### ■ Features

- Fast Switching Speed
- Ultra-Small Surface Mount Package
- For General Purpose Switching Applications
- High Conductance



### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	100	V
Peak Repetitive Reverse Voltage	$V_{RRM}$	75	V
Working Peak Reverse Voltage	$V_{RWM}$		
DC Blocking Voltage	$V_R$		
RMS Reverse Voltage	$V_{R(RMS)}$	53	V
Forward Continuous Current	$I_{FM}$	215	mA
Non-Repetitive Peak Forward Surge Current @ $t = 1.0 \mu\text{s}$	$I_{FSM}$	2.0	A
@ $t = 1.0\text{ms}$		1.0	
@ $t = 1.0\text{s}$		0.5	
Power Dissipation	$P_d$	200	mW
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	625	K/W
Operating and Storage Temperature Range	$T, T_{STG}$	-65 to +150	$^\circ\text{C}$

### ■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Maximum Forward Voltage	$V_{FM}$	$I_F = 1.0\text{mA}$			0.715	V
		$I_F = 10\text{mA}$			0.855	
		$I_F = 50\text{mA}$			1.0	
		$I_F = 150\text{mA}$			1.25	
Maximum Peak Reverse Current	$I_{RM}$	$V_R = 75\text{V}$			2.5	$\mu\text{A}$
		$V_R = 75\text{V}, T_j = 150^\circ\text{C}$			50	$\mu\text{A}$
		$V_R = 25\text{V}, T_j = 150^\circ\text{C}$			30	$\mu\text{A}$
		$V_R = 20\text{V}$			25	nA
Junction Capacitance	$C_j$	$V_R = 0, f = 1.0\text{MHz}$			2	pF
Reverse Recovery Time	$t_{rr}$	$I_F = I_R = 10\text{mA}, I_{rr} = 0.1 \times I_R, R_L = 100 \Omega$			4	ns

### ■ Marking

Marking	KJG
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